L Number	Hits	Search Text	DB	Time stamp
1	27375	semiconductor and (tft or (thin adj film	USPAT;	2004/03/02
		adj transistor))	US-PGPUB;	09:51
			EPO; JPO; DERWENT;	
			IBM_TDB	
2	343		USPAT;	2004/03/02
		adj transistor))) and (alno or alon or	US-PGPUB;	09:53
		((aluminum adj nitride) and oxygen))	EPO; JPO;	
			DERWENT;	
3	343	((semiconductor and (tft or (thin adj	USPAT;	2004/03/02
		film adj transistor))) and (alno or alon	US-PGPUB;	10:41
		or ((aluminum adj nitride) and oxygen)))	EPO; JPO;	
		and substrate	DERWENT;	1
			IBM_TDB	0004/02/02
4	237	(semiconductor and (tft or (thin adj film	USPAT;	2004/03/02
		adj transistor))) and (alnc or alcn or ((aluminum adj nitride) and carbon))	US-PGPUB; EPO; JPO;	10:42
		((aruminum adj nittride) and carbon))	DERWENT;	
			IBM TDB	